MC14002B
See Page 6-5

MC14002UB
See Page 6-14

MOTOROLA

MC14006B

CMOS MSI

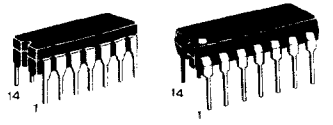
(LOW-POWER COMPLEMENTARY MOS)

18-BIT STATIC SHIFT REGISTER

18-BIT STATIC SHIFT REGISTER

The MC14006B shift register is comprised of four separate shift register sections sharing a common clock: two sections have four stages, and two sections have five stages with an output tap on both the fourth and fifth stages. This makes it possible to obtain a shift register of 4, 5, 8, 9, 10, 12, 13, 14, 16, 17, or 18 bits by appropriate selection of inputs and outputs. This part is particularly useful in serial shift registers and time delay circuits.

- Output Transitions Occur on the Falling Edge of the Clock Pulse
- Fully Static Operation
- Can be Cascaded to Provide Longer Shift Register Lengths
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4006B



L SUFFIX
CERAMIC PACKAGE
CASE 632

P SUFFIX
PLASTIC PACKAGE
CASE 646

ORDERING INFORMATION

A Series = 55°C to + 125°C
MC14XXXBAL (Ceramic Package Only)
C Series = 40°C to + 85°C
MC14XXXBCP (Plastic Package)
MC14XXXBCL (Ceramic Package)

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	0.5 to + 18.0	V
V_{in}, V_{out}	Input or Output Voltage (DC or Transient)	0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
P_D	Power Dissipation, per Package†	500	mW
T_{stg}	Storage Temperature	65 to + 150	°C
T_L	Lead Temperature (8-Second Soldering)	260	°C

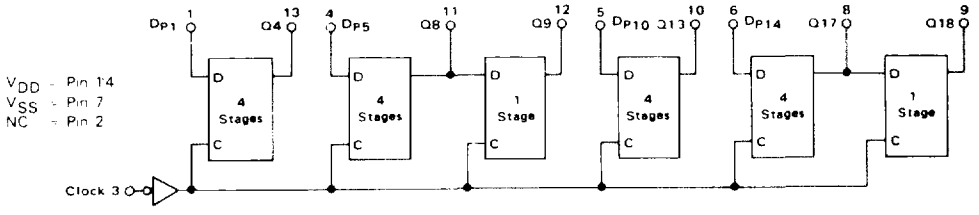
*Maximum Ratings are those values beyond which damage to the device may occur.
†Temperature Derating: Plastic "P" Package: 12mW/°C from 65°C to 85°C
Ceramic "L" Package: 12mW/°C from 100°C to 125°C

TRUTH TABLE
(Single Stage)

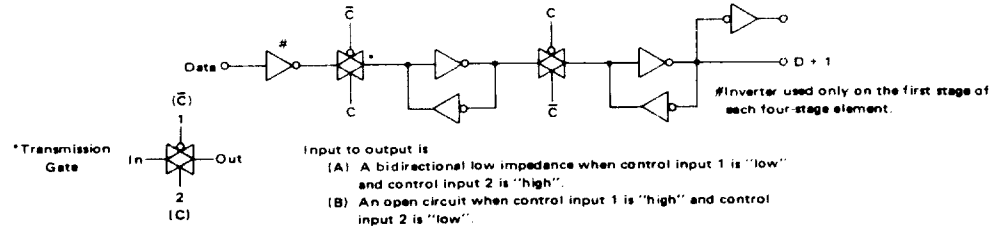
X = Don't Care

D_n	C	Q_{n+1}
0	⌐⌙	0
1	⌐⌙	1
X	⌙⌐	Q_n

BLOCK DIAGRAM



LOGIC DIAGRAM
(ONE REGISTER STAGE)



#Inverter used only on the first stage of each four-stage element.

Input to output is
(A) A bidirectional low impedance when control input 1 is "low" and control input 2 is "high".
(B) An open circuit when control input 1 is "high" and control input 2 is "low".

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ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	T_{low}* Min	T_{low}* Max	25°C Min	25°C Typ #	25°C Max	T_{high}* Min	T_{high}* Max	Unit
Output Voltage "0" Level	V_{OL}	5.0	–	0.05	–	0	0.05	–	0.05	Vdc
V_{in} = V_{DD} or 0		10	–	0.05	–	0	0.05	–	0.05	
		15	–	0.05	–	0	0.05	–	0.05	
"1" Level	V_{OH}	5.0	4.95	–	4.95	5.0	–	4.95	–	Vdc
V_{in} = 0 or V_{DD}		10	9.95	–	9.95	10	–	9.95	–	
		15	14.95	–	14.95	15	–	14.95	–	
Input Voltage "0" Level	V_{IL}									Vdc
(V_O = 4.5 or 0.5 Vdc)		5.0	–	1.5	–	2.25	1.5	–	1.5	
(V_O = 9.0 or 1.0 Vdc)		10	–	3.0	–	4.50	3.0	–	3.0	
(V_O = 13.5 or 1.5 Vdc)		15	–	4.0	–	6.75	4.0	–	4.0	
"1" Level	V_{IH}									
(V_O = 0.5 or 4.5 Vdc)		5.0	3.5	–	3.5	2.75	–	3.5	–	Vdc
(V_O = 1.0 or 9.0 Vdc)		10	7.0	–	7.0	5.50	–	7.0	–	
(V_O = 1.5 or 13.5 Vdc)		15	11.0	–	11.0	8.25	–	11.0	–	
Output Drive Current (AL Device)	I_{OH}									mAdc
(V_{OH} = 2.5 Vdc) Source		5.0	−3.0	–	−2.4	−4.2	–	−1.7	–	
(V_{OH} = 4.6 Vdc)		5.0	−0.64	–	−0.51	−0.88	–	−0.36	–	
(V_{OH} = 9.5 Vdc)		10	−1.6	–	−1.3	−2.25	–	−0.9	–	
(V_{OH} = 13.5 Vdc)		15	−4.2	–	−3.4	−8.8	–	−2.4	–	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	5.0	0.64	–	0.51	0.88	–	0.36	–	mAdc
(V_{OL} = 0.5 Vdc)		10	1.6	–	1.3	2.25	–	0.9	–	
(V_{OL} = 1.5 Vdc)		15	4.2	–	3.4	8.8	–	2.4	–	
Output Drive Current (CL/CP Device)	I_{OH}									mAdc
(V_{OH} = 2.5 Vdc) Source		5.0	−2.5	–	−2.1	−4.2	–	−1.7	–	
(V_{OH} = 4.6 Vdc)		5.0	−0.52	–	−0.44	−0.88	–	−0.36	–	
(V_{OH} = 9.5 Vdc)		10	−1.3	–	−1.1	−2.25	–	−0.9	–	
(V_{OH} = 13.5 Vdc)		15	−3.6	–	−3.0	−8.8	–	−2.4	–	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	5.0	0.52	–	0.44	0.88	–	0.36	–	mAdc
(V_{OL} = 0.5 Vdc)		10	1.3	–	1.1	2.25	–	0.9	–	
(V_{OL} = 1.5 Vdc)		15	3.6	–	3.0	8.8	–	2.4	–	
Input Current (AL Device)	I_{in}	15	–	±0.1	–	±0.00001	±0.1	–	±1.0	µAdc
Input Current (CL/CP Device)	I_{in}	15	–	±0.3	–	±0.00001	±0.3	–	±1.0	µAdc
Input Capacitance (V_{in} = 0)	C_{in}	–	–	–	–	5.0	7.5	–	–	pF
Quiescent Current (AL Device) (Per Package)	I_{DD}	5.0	–	5.0	–	0.005	5.0	–	150	µAdc
		10	–	10	–	0.010	10	–	300	
		15	–	20	–	0.015	20	–	600	
Quiescent Current (CL/CP Device) (Per Package)	I_{DD}	5.0	–	20	–	0.005	20	–	150	µAdc
		10	–	40	–	0.010	40	–	300	
		15	–	80	–	0.015	80	–	600	
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0	I_T = (1.3 µA/kHz) f + I_{DD}							µAdc
		10	I_T = (2.6 µA/kHz) f + I_{DD}							
		15	I_T = (3.9 µA/kHz) f + I_{DD}							

*T_{low} = −55°C for AL Device, −40°C for CL/CP Device.
T_{high} = +125°C for AL Device, +85°C for CL/CP Device

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

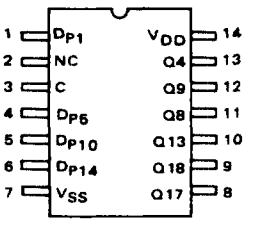
**The formulas given are for the typical characteristics only at 25°C

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$$

where: I_T is in µA (per package), C_L in pF, V = (V_{DD} − V_{SS}) in volts, f in kHz is input frequency, and k = 0.001

PIN ASSIGNMENT



NC = No Connection

SWITCHING CHARACTERISTICS* (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD}	Min	Typ #	Max	Unit
Output Rise and Fall Time	t_{TLH},					ns
t_{TLH}, t_{THL} = (1.5 ns/pF) C_L + 25 ns	t_{THL}	5.0	–	100	200	
t_{TLH}, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns		10	–	50	100	
t_{TLH}, t_{THL} = (0.55 ns/pF) C_L + 9.5 ns		15	–	40	80	
Propagation Delay Time	t_{PLH}					ns
t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 220 ns	t_{PHL}	5.0	–	300	600	
t_{PLH}, t_{PHL} = (0.66 ns/pF) C_L + 77 ns		10	–	110	220	
t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 55 ns		15	–	80	160	
Clock Pulse Width	t_{WH}	5.0	200	100	–	ns
		10	120	60	–	
		15	80	40	–	
Clock Pulse Frequency	f_{cl}	5.0	–	5.0	2.5	MHz
		10	–	8.3	4.2	
		15	–	12	6.0	
Clock Pulse Rise and Fall Time**	t_{TLH}	5.0	–	–	15	μs
	t_{THL}	10	–	–	5	
		15	–	–	4	
Setup Time	t_{su}	5.0	0	-50	–	ns
		10	0	-15	–	
		15	0	-8.0	–	
Hold Time	t_h	5.0	180	75	–	ns
		10	90	25	–	
		15	75	20	–	

*The formulas given are for the typical characteristics only at 25°C.

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

**When shift register sections are cascaded, the maximum rise and fall times of the clock input should be equal to or less than the rise and fall times of the data outputs driving data inputs, plus the propagation delay of the output driving stage for the output capacitance load.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

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FIGURE 1 – TYPICAL OUTPUT SOURCE CURRENT CHARACTERISTICS TEST CIRCUIT

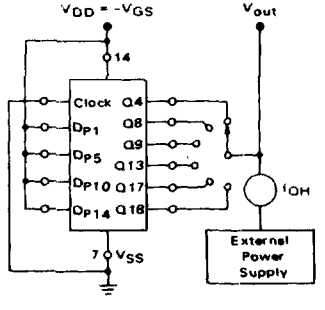

FIGURE 2 – TYPICAL OUTPUT SINK CURRENT CHARACTERISTICS TEST CIRCUIT

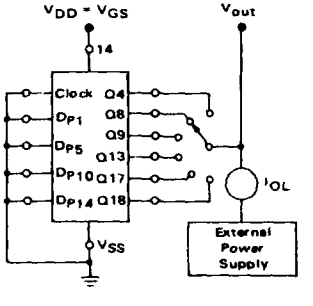

FIGURE 3 – POWER DISSIPATION TEST CIRCUIT AND WAVEFORM

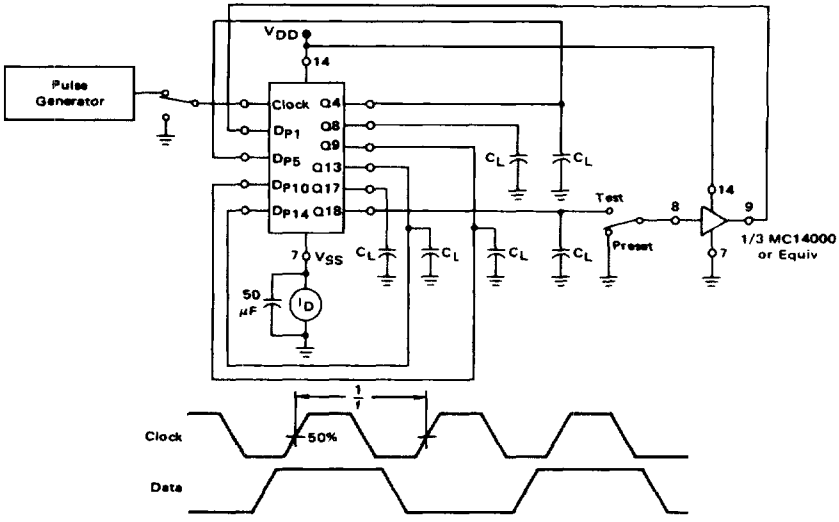

FIGURE 4 – SWITCHING TIME TEST CIRCUIT AND WAVEFORMS